

RKP409KS

Composite Pin Diode for Antenna Switching

REJ03G1501-0200 Rev.2.00 Jun 08, 2007

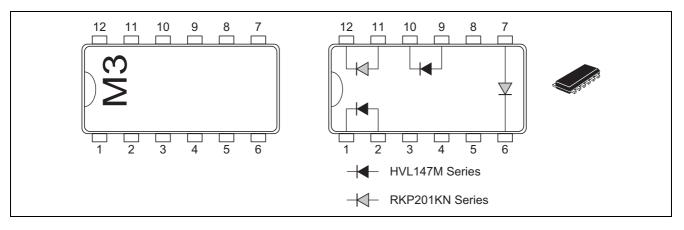
Features

- An optimal solution for antenna switching in mobile phones.
- Low capacitance. (C = 0.35 pF max)
- Low forward resistance. (rf = $2.0 \Omega \text{ max } @I_F = 2 \text{ mA}$, f = 100 MHz)
- Thin outline of diode array with four different kind of elements (MFP12) is suitable for surface mount design.

Ordering Information

Part No.	Laser Mark	Package Name	Package Code	
RKP409KS	M3	MFP12	PUSF0012ZA-A	

Pin Arrangement



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Value	Unit
Reverse voltage	V _R	30	V
Forward current	lF	100	mA
Power dissipation	Pd *	100	mW
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	٥C

Note: Per one device

Electrical Characteristics (HVL147M Series)

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	IR	_	—	100	nA	V _R = 30 V
Forward voltage	V _F	_	—	1.0	V	I _F = 10 mA
Capacitance	С		_	0.31	pF	V _R = 1 V, f = 1 MHz
Forward resistance	r _{f1}	_	—	2.5	Ω	I _F = 2 mA, f = 100 MHz
	r _{f2}	_	—	1.5	Ω	I _F = 10 mA, f = 100 MHz
ESD-Capability *1	—	100	—	—	V	$C = 200 \text{ pF}, R = 0 \Omega$, Both forward
						and reverse direction 1 pulse.

Electrical Characteristics (RKP201KN Series)

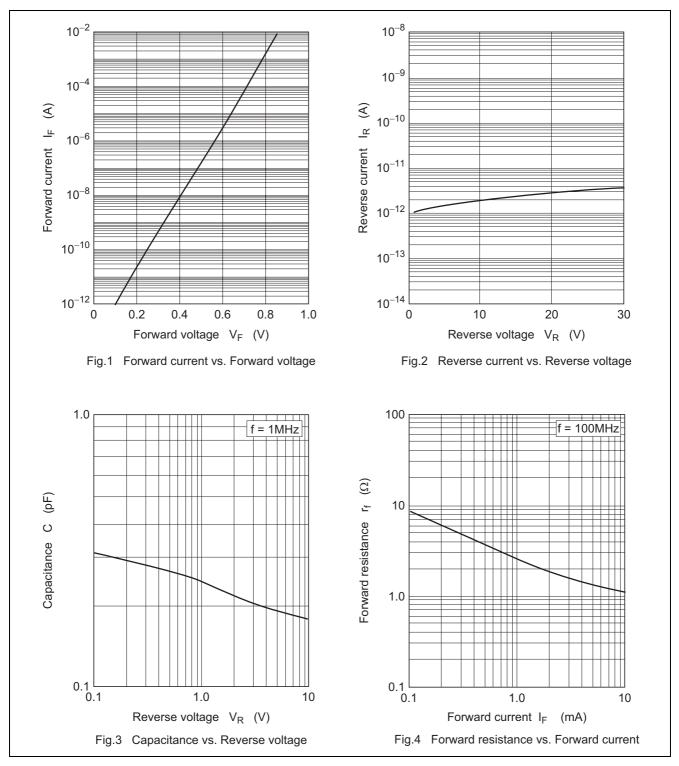
(Ta = 25°C)

ltem	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _R	—	—	100	nA	V _R = 30 V
Forward voltage	VF	—	—	0.9	V	I _F = 2 mA
Capacitance	С	—	—	0.35	pF	$V_R = 1 V$, f = 1 MHz
Forward resistance	r _f	—	—	2.0	Ω	I _F = 2 mA, f = 100 MHz
ESD-Capability *1	—	100	—	—	V	$C = 200 \text{ pF}, R = 0 \Omega$, Both forward
						and reverse direction 1 pulse.

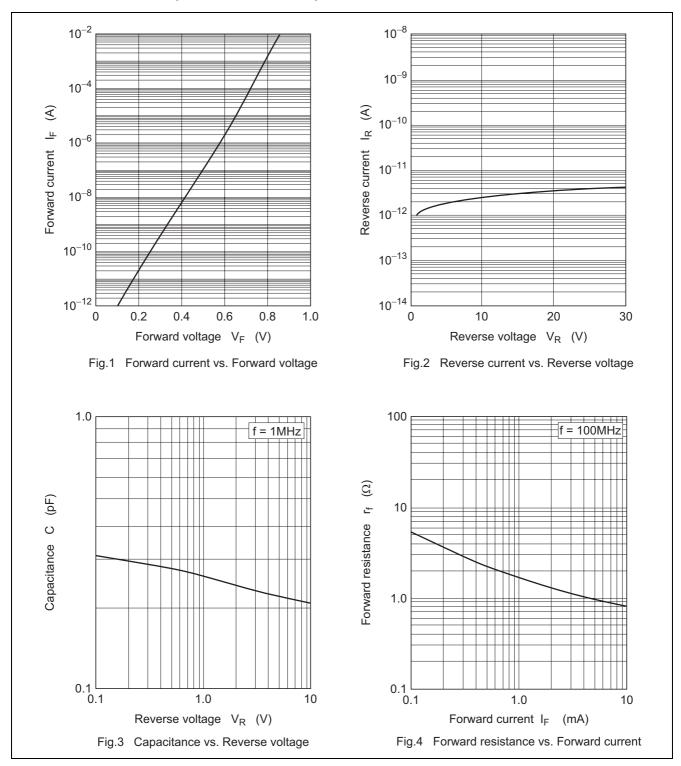
Notes: 1. Failure criterion ; $I_R > 100 \ nA$ at V_R = 30 V

2. For MFP12 package, the material of lead is exposed for cutting plane. There for, soldering nature of lead tip part is considered as unquestioned. Please kindly consider soldering nature.





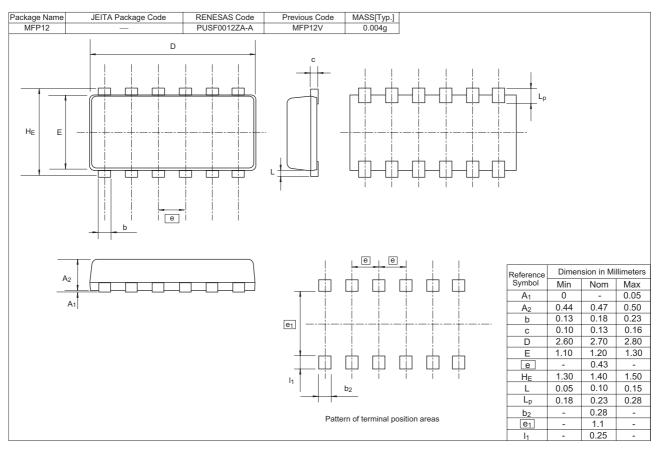
RENESAS



Main Characteristic (RKP201KN Series)

RENESAS

Package Dimensions



RenesasTechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan



RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

http://www.renesas.com